	Specification	Symbol	Condition / Comment				901-15-SiC Unit			
	Maximum Operating Voltage	$V_{O(max)}$	I _{off} < 40 μADC, T _{case} = 70°C				90 kVDC			kVDC
RATINGS	Maximum Isolation Voltage	VI	Between HV switch and control / GND, continuously					120		
	Max. Housing Insulation Voltage	V _{INS}	Between switch						150	kVDC
	Maximum Turn-On Peak Current	I _{P(max)}	T _{case} = 25°C	•					150	
		()		t _p < 1 ms, duty cycle <1%					100	
				t _p < 10 ms, duty cycle <1% t _p < 100 ms, duty cycle <1%					65	
									45	ADC
MAXIMUM	Maximum Continuous Load Current	I _{L(max)}		Standard devices					10	
		·L(IIIax)	T _{case} = 25°C	Option CF, cooling fins Devices with option DLC					15	
Ž			1 5000					20		
	Max. Continuous Power Dissipation	P _{d(max)}			Standard devices & FC, forced air 4 m/s			30		
Ţ	·	, ,	T _{case} = 25°C	Devices wi					3000	Watt
4BSOLUTE	Linear Derating		A1 0500	Standard of	evices & FC, forced air 4 m/s				0.44	
SO	· ·		Above 25°C	Devices with option DLC					60	W/K
48	Operating Temperature Range	To	Standard device	andard devices & options ILC, DLC					-4070 (60)	°C
	Storage Temperature Range	Ts	Switches with o	ption ILC ma	ay require	frost protection!			-4090	°C
	Max. Permissible Magnetic Field	В	Homogeneous s	Homogeneous steady-field, surrounding the whole switch				25		
	Max. Auxilliary Voltage	V _{aux}	Built-in overvolta	age limiter (re	, ,				5.5	VDC
	Permissible Operating Voltage	Vo	Unipolar operati	polar operation (one switch pole grounded or floated)				0 ± 90		
	Range			polar operation (positive & negative voltage applied)				0 ± 45		
CTERISTICS	Typical Breakdown Voltage	V_{br}		NOTE: V_{br} is a test parameter for quality control purposes only. Not applicable in normal operation!				± 99		
	Typical Off-State Current	l _{off}			.70°C, reduced I _{off} on request			40		
	Typical Turn-On Resistance	R _{stat}	Each switching			nax), T _{case} =25°C			3.04	μADC
	rypical ruin-On Nesisiance R					nax), T case = 25 °C			6.00	
						nax), T case = 23 °C nax), T case = 70 °C			15.10	Ohm
	Typical Capacitive Power	P _{dc}	Switch capacita	nces only-	0.8 x V _O		3,13			Olilli
	Dissipation of Switch	· uc	without external	•	$_{\text{(max)}}$, $f = 100$ Hz		31.3			
	(Natural Power Dissipation)		parasitic capaci			_{(max),} f = 10000Hz			313	Watt
	Typical Propagation Delay Time	t _{d(on)}	Resistive load, 0.1 x I _{P(max)} , 0.8 x V _{O(max)} , 50-50%					200		
	Typical Output Pulse Jitter	t _i	Impedance matched input, V _{aux} / V _{ctrl} = 5.00 VDC					2		
SIZ	Typical Ouput Transition Time	t _r , t _f	Resistive load,	10-90%	0.1 x V	$O(max)$, $I_L = 0.1 \times I_{p(max)}$			20	
NA NA	(Rise Time)					$O(max)$, $I_L = 0.1 \times I_{p(max)}$	40		40	
			$0.8 \times V_{O(max)}$, $I_L = 1.0 \times I_{p(max)}$				80			
8	Maximum Turn-On Time	t _{on(max)}	No limitation					∞ [
1	Minimum Turn-On Time	t _{on(min)}	can be customized. Please consult factory				250 ns			ns
0	Max. Continuous Switching	$f_{(max)}$	@ V _{aux} = 5.00 V		tandard devices without HFS option			7		
14.	Frequency		Sw. shutdown if f _(max) is		devices with HFS supply		30			
K			Sw. snutdown if T _(max) is Opt. HFS + sufficient cooling option				70			kHz
12	M : D :5									
ELECTRICAL	Maximum Burst Frequency	f _{b(max)}						1 MH 10 (Use burst option HFB for >10 pulses) Puls		
4	Maximum Number of Pulses / Burst	N _(max)						` ' '		
	Coupling Capacitance	Cc	Switch against control side						< 100	pF pF
	Natural Capacitance	C _N			i, @ 0.8 x V _{O(max)}			< 20		
	Control Voltage Range	V _{ctrl}		The V _{ctrl} has no impact on the output pulse shape.				3 10 VI		
	Auxiliary Supply Voltage Range	V _{aux}	The +5 V supply is not required in the HFS mode.				4.5 5.5			VDC
	Typical Auxiliary Supply Current	l _{aux}	$V_{aux} = 5.00 \text{ VDC}$, $T_{case} = 25^{\circ}\text{C}$. $0.01 \text{ x f}_{(max)}$				200 500 15			ADC
	Ont LIEC Est Complex/altern 1/4	1/	Active current limitation above 1A. @ specified f _(max)							mADC
	Opt. HFS, Ext. Supply Voltage V1	V _{HFS(V1)}	Stability ±3%, current consumption <0.4 mA/kHz @ 25°C							VDC
	Opt. HFS, Ext. Supply Voltage V2	V _{HFS(V2)}	Stability ±3%, current consumption <0.5 mA/kHz @ 25°C				160			VDC
	Intrinsic Diode Forward Voltage	V _F	$T_{case} = 25^{\circ}C$, $I_{F} = 0.3 \times I_{P(max)}$				20			VDC
	Diode Reverse Recovery Time	t _{rrc}	$T_{case} = 25^{\circ}C$, $I_F = 0.3 \text{ x } I_{P(max)}$, $di/dt = 100 \text{ A/µs}$				50			ns
8	Dimensions	LxWxH	Devices with options DLC				Please consult BEHLKE!			°
ISI										mm ³
FUNCTIONS HOUSING	Weight	Standard housing				Please consult BEHLKE!				
		Devices with options DLC				9				
	Control Signal Input	mo Pin 1: TTL co	o Pin 1: TTL compatible (LS-C: With 100Ω termination). Schn					stics. Control voltage 2-10 V (3-5 V for low j	itter).	
	ogic GND / 5V Return Lemo Shielding: The logic ground is internally connected with the safety earthing terminal (threaded inserts).									
	5V Auxiliary Supply	· · · · · · · · · · · · · · · · · · ·							Higher rep rates require option HFS.	
	Fault Signal Output	· · · · · · · · · · · · · · · · · · ·					Iriver over-heat, over-frequency, low auxiliary voltage. L = Fault.			
	Inhibit Signal Input	Lemo Pin 2: TTL compatible, Schmitt-Trigger characteristics for								
	LED Indicators • • •	· · · · · · · · · · · · · · · · · · ·					ntrol signal received, switch ON". • "Red: "Fault condition, switch OFF"			
	7, 2						nermotrigger 75°C, response time < 60 s @ $3xPd(max)$, $\Delta T=25K$ (50 to 75°C).			
	Temperature Protection DLC Cooling		ches with option DLC: 65°C, response time < 3 s @ 3xPd(max),							
ORDERING			Option LP Low Pass. Input filter for increased noise immunity.				on FO-I	Fibre Optics Input fort the inhibit and PPC signal	1.	
	HTS 901-15-SiC	Option HFB High Frequency Burst (improved capability by external					on FO-F	Fibre Optics Output for the fault signal		
	Solid State Switch, 90 kV, 150	Option HFS High Frequency Switching (two auxiliary supply inputs V1 &				(V2) Optio	on UL-94	Flame retardant casting resin, UL94-V0		
		Option S-TT Soft Transition Time decrease the rise and fall time by 20% Option Min-On Individually increased "Min On-Time" to avoid unwanted					on I-FWD	Integrated Free-Wheeling Diode. In connection with inductive lo		
	For further ordering options please	Option Min-On Individually increased "Min. On-Time" to avoid unwanted Option Min-Off Individually increased "Min. Off-Time" to avoid unwanted					on I-FWDN on LC-AH-DR	Integrated Freewheeling Diode Network. In connection with inc Removeable Power Driver, DLC cooling, solid aluminum housi		
	to our on-line catalog, section C https://www.behlke.com/separations/sep	Option PPC Pulse Pause Control for pauses between pos. and neg. pul					on SEP-C	Separated control unit. Control unit with LED indicators in a sep	_	
	4.htm	Option ISO-80 80kV Isolation. Isolation Voltage increased to 80kV.					on I-PC	Integrated part components according to customer specifi		
	DELII VE	Option ISO-120 120kV Isolation. Isolation Voltage increased to 120kV.					on PCC	Pulser Configuration. Switch combined with custom speci	•	
	DEULVE		Option ISO-160 160kV Isolation. Isolation Voltage increased to 160kV. Option ISO-200 200kV Isolation. Isolation Voltage increased to 200kV.					on CF on GCF	Copper Cooling Fins. $P_{d(max)}$ can be increased by the factor Grounded Cooling Flange. $P_{d(max)}$ can be increased by the factor $P_{d(max)}$ can be increased by $P_{d(max)}$ can be increased by the factor $P_{d(max)}$ can be increased by the factor $P_{d(max)}$ can be increased by $P_{d(max)}$.	
	HIGH-TECH IN HIGH VOLTAG	E	Option ISO-200 200kV Isolation. Isolation Voltage increased to 200kV. Option FO-C Fibre Optics Input for the control input				on GCF on DLC	Direct Liquid Cooling. P _{d(max)} can be increased by the factor 10		
Cust	omized switching units are available on reque	st. All data	and specifications subject to change without notice. Please visit www.behl						5-SiC Revision 18.08.2025 ©2012 All rights reser	